



FCX619

50V NPN LOW SATURATION POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > 50V
- I_C = 3A High Continuous Collector Current
- I_{CM} up to 6A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < 220mV @ 1A
- R_{CE(sat)} = 87mΩ @ 2.75A for a Low Equivalent On-Resistance
- hFE Characterized up to 6A for High Current Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

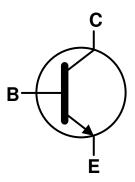
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.052 grams (Approximate)

Applications

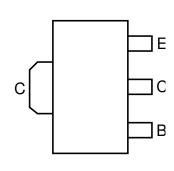
- Load Management Functions
- Motor Control
- DC-DC / DC-AC Converters







Device Symbol



Top View Pin-Out

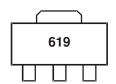
Ordering Information (Notes 4 and 5)

Part number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX619TA	AEC-Q101	619	7	12	1,000
FCX619-13R	AEC-Q101	619	13	12	4,000
FCX619QTA	Automotive	619	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



619 = Product Type Marking Code



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	3	Α
Peak Pulse Current	Ісм	6	Α
Continuous Base Current	I _B	500	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		0.7		
Dower Discinstian	(Note 7)		1.0	W	
Power Dissipation	(Note 8)	P _D	1.5		
	(Note 9)		2.0		
	(Note 6)		178		
Thermal Desistance, Juneties to Ambient Air	(Note 7)	$R_{ hetaJA}$	125	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 8)		83		
	(Note 9)		62.5		
Thermal Resistance, Junction to Lead	(Note 10)	$R_{ heta JL}$	6		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

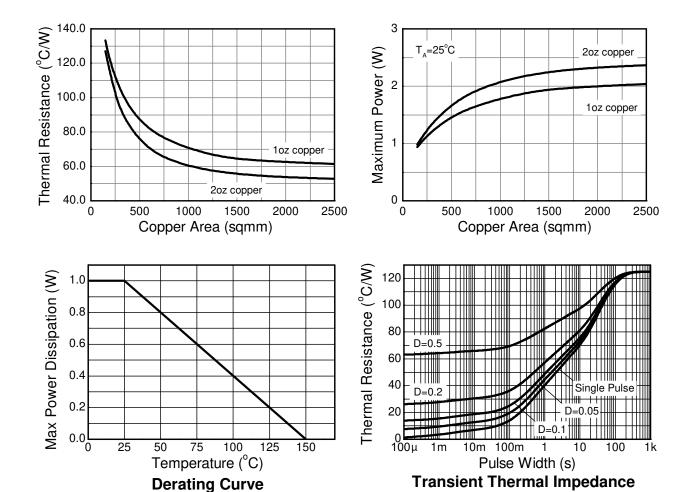
Notes:

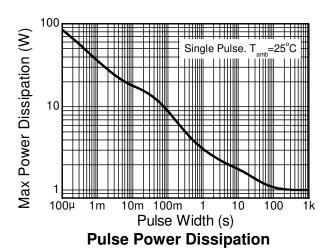
- 6. For a device mounted with the exposed collector pad on minimum recommended pad layout (MRP) 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 7. Same as Note 6, except the device is mounted with the exposed collector pad on 15mm x 15mm 1oz copper.
 8. Same as Note 6, except the device is mounted with the exposed collector pad on 25mm x 25mm 1oz copper.
 9. Same as Note 6, except the device is mounted with the exposed collector pad on 40mm x 40mm 1oz copper.

- 10. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information







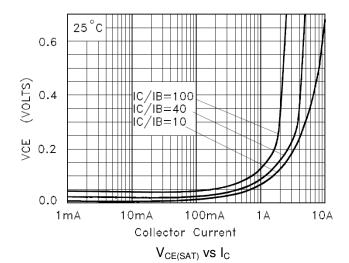
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

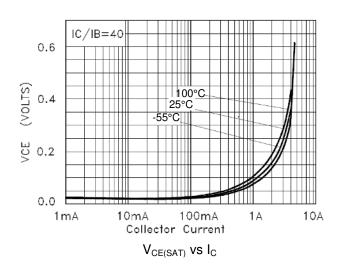
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	50	190	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 12)	BV _{CEO}	50	65	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.3	_	V	$I_E = 100 \mu A$
Collector Cutoff Current	I _{CBO}	_	_	100	nA	V _{CB} = 40V
Emitter Cutoff Current	I _{EBO}	_	_	100	nA	V _{EB} = 5.6V
Emitter Cutoff Current	Ices	_	_	100	nA	V _{CES} = 40V
DC Current Transfer Static Ratio (Note 12)	h _{FE}	200 300 200 100	400 450 400 200 30	_	I	$\begin{split} &I_{C} = 10 mA, \ V_{CE} = 2 V \\ &I_{C} = 200 mA, \ V_{CE} = 2 V \\ &I_{C} = 1A, \ V_{CE} = 2 V \\ &I_{C} = 2A, \ V_{CE} = 2 V \\ &I_{C} = 6A, \ V_{CE} = 2 V \end{split}$
Collector-Emitter Saturation Voltage (Note 12)	V _{CE(sat)}	_	13 150 190 240	25 220 260 320	mV	$I_C = 100$ mA, $I_B = 10$ mA $I_C = 1$ A, $I_B = 10$ mA $I_C = 2$ A, $I_B = 50$ mA $I_C = 2.75$ A, $I_B = 100$ mA
Base-Emitter Saturation Voltage (Note 12)	$V_{BE(sat)}$		0.97	1.1	V	$I_C = 2.75A$, $I_B = 100mA$
Base-Emitter Turn-On Voltage (Note 12)	$V_{BE(on)}$	_	0.89	1	V	$I_C = 2.75A, V_{CE} = 2V$
Transitional Frequency	f_T	100	165	1	MHz	$I_C = 50 \text{mA}, V_{CE} = 10 \text{V}$ f = 100MHz
Output Capacitance	C_{obo}	_	12	20	pF	$V_{CB} = 10V$, $f = 1MHz$,
Turn-On Time	t _(on)	_	170	_	ns	$V_{CC} = 10V, I_{C} = 1A$
Turn-Off Time	$t_{(\text{off})}$	_	750	_	ns	$I_{B1} = 10 \text{mA},$ $I_{B2} = -10 \text{mA}$

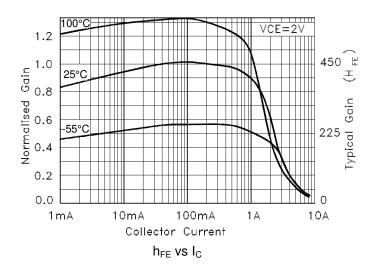
Note: 12. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

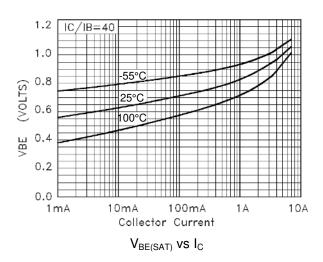


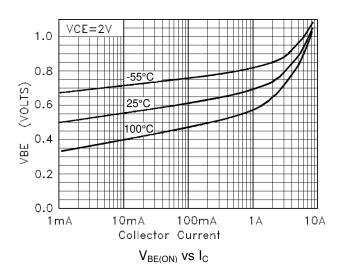
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)









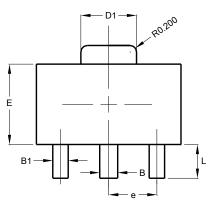


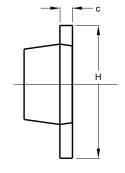


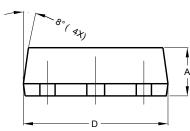
Package Outline Dimensions

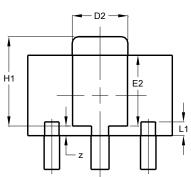
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89







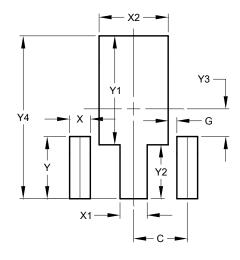


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)		
С	1.500		
G	0.244		
X	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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